## FEATURES

High speed
-3 dB bandwidth ( $G=1, R_{L}=100 \Omega$ ): 1050 MHz
Slew rate: 870 V/ $/ \mathrm{s}$
$0.1 \%$ settling time: 9 ns
Input bias current: 2 pA typical
Input capacitance
Common-mode capacitance: 1.3 pF typical
Differential mode capacitance: 0.1 pF typical
Low input noise

Current noise: $2.5 \mathrm{fA} / \sqrt{ } \mathrm{Hz}$ at 100 kHz
Low distortion: - $\mathbf{9 0} \mathbf{~ d B c}$ at $\mathbf{1 0 ~ M H z ~ ( G = 1 , ~} \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$ )
Linear output current: 40 mA
Supply quiescent current per amplifier: 19 mA typical
Powered down supply quiescent current per amplifier:
1.5 mA typical

## APPLICATIONS

Photodiode amplifiers
Data acquisition front ends
Instrumentation
Filters
ADC drivers
Output buffers

CONNECTION DIAGRAMS


NOTES

1. NIC = No INTERNAL CONNECTION. A.

Figure 1. 8-Lead LFCSP (CP-8-13)


NOTES

1. NIC = NO INTERNAL CONNECTION.
Figure 2. 8-Lead SOIC (RD-8-1)

ADA4817-2
TOP VIEW
(Not to Scale)


NOTES

1. NIC = NO INTERNAL CONNECTION.

Figure 3. 16-Lead LFCSP (CP-16-20)

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## GENERAL DESCRIPTION

The ADA4817-1 (single) and ADA4817-2 (dual) FastFET ${ }^{\text {m }}$ amplifiers are unity-gain stable, ultrahigh speed, voltage feedback amplifiers with FET inputs. These amplifiers were developed with the Analog Devices, Inc., proprietary eXtra fast complementary bipolar (XFCB) process, which allows the amplifiers to achieve ultralow noise ( $4 \mathrm{nV} / \sqrt{ } \mathrm{Hz} ; 2.5 \mathrm{fA} / \sqrt{ } \mathrm{Hz}$ ) as well as very high input impedances.
With 1.3 pF of input capacitance, low noise ( $4 \mathrm{nV} / \sqrt{ } \mathrm{Hz}$ ), low offset voltage ( 2 mV maximum), and $1050 \mathrm{MHz}-3 \mathrm{~dB}$ bandwidth, the ADA4817-1/ADA4817-2 are ideal for data acquisition front ends as well as wideband transimpedance applications, such as photodiode preamps.

With a wide supply voltage range from 5 V to 10 V and the ability to operate on either single or dual supplies, the ADA4817-1/ ADA4817-2 are designed to work in a variety of applications including active filtering and analog-to-digital converter (ADC) driving. The ADA4817-1 is available in a $3 \mathrm{~mm} \times 3 \mathrm{~mm}, 8$-lead LFCSP and 8 -lead SOIC, and the ADA4817-2 is available in a $4 \mathrm{~mm} \times 4 \mathrm{~mm}$, 16-lead LFCSP. These packages feature a low distortion pinout that improves second harmonic distortion and simplifies circuit board layout. They also feature an exposed pad that provides a low thermal resistance path to the printed circuit board (PCB). The EPAD enables more efficient heat transfer and increases reliability. These products are rated to work over the extended industrial temperature range $\left(-40^{\circ} \mathrm{C}\right.$ to $\left.+105^{\circ} \mathrm{C}\right)$.

## SPECIFICATIONS

$\pm 5$ V OPERATION
$\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C},+\mathrm{V}_{\mathrm{S}}=5 \mathrm{~V},-\mathrm{V}_{\mathrm{S}}=-5 \mathrm{~V}, \mathrm{G}=1, \mathrm{R}_{\mathrm{F}}=348 \Omega$ for $\mathrm{G}>1, \mathrm{R}_{\mathrm{L}}=100 \Omega$ to ground, unless otherwise noted.
Table 1.

| Parameter | Test Conditions/Comments | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| DYNAMIC PERFORMANCE <br> -3 dB Bandwidth <br> Gain Bandwidth Product <br> Full Power Bandwidth <br> 0.1 dB Flatness <br> Slew Rate <br> Settling Time to 0.1\% | $\begin{aligned} & \text { V out }=0.1 \mathrm{~V} \text { p-p } \\ & \mathrm{V}_{\text {out }}=2 \mathrm{~V} \text { p-p } \\ & \mathrm{V}_{\text {out }}=0.1 \mathrm{Vp}-\mathrm{p}, \mathrm{G}=2 \\ & \mathrm{~V}_{\text {out }}=0.1 \mathrm{Vp}-\mathrm{p} \\ & \mathrm{~V}_{\text {IN }}=3.3 \mathrm{Vp}-\mathrm{p}, \mathrm{G}=2 \\ & \mathrm{~V}_{\text {out }}=2 \mathrm{~V} \text { p-p, } \mathrm{R}_{\mathrm{L}}=100 \Omega, \mathrm{G}=2 \\ & \mathrm{~V}_{\text {out }}=4 \mathrm{~V} \text { step } \\ & \mathrm{V}_{\text {out }}=2 \mathrm{~V} \text { step, } \mathrm{G}=2 \end{aligned}$ |  | 1050 200 390 $\geq 410$ 60 60 870 9 |  | MHz <br> MHz <br> MHz <br> MHz <br> MHz <br> MHz <br> V/ $\mu \mathrm{s}$ ns |
| NOISE/HARMONIC PERFORMANCE <br> Harmonic Distortion $\begin{gathered} \mathrm{f}=1 \mathrm{MHz} \\ \mathrm{HD} 2 \\ \mathrm{HD} 3 \end{gathered}$ $\mathrm{f}=10 \mathrm{MHz}$ <br> HD2 <br> HD3 <br> $\mathrm{f}=50 \mathrm{MHz}$ <br> HD2 <br> HD3 <br> Input Voltage Noise <br> Input Current Noise | $\begin{aligned} & \text { Vout }=2 \mathrm{Vp}-\mathrm{p}, \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega \\ & \text { Vout }=2 \mathrm{Vp}-\mathrm{p}, \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega \\ & \text { Vout }=2 \mathrm{Vp}-\mathrm{p}, \mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega \\ & \mathrm{f}=100 \mathrm{kHz} \\ & \mathrm{f}=100 \mathrm{kHz} \end{aligned}$ |  | $\begin{aligned} & -113 \\ & -117 \\ & -90 \\ & -94 \\ & -64 \\ & -66 \\ & 4 \\ & 2.5 \end{aligned}$ |  | dBc <br> dBc <br> dBc <br> dBc <br> dBc <br> dBc <br> $\mathrm{nV} / \sqrt{ } \mathrm{Hz}$ <br> fA/ $\sqrt{\mathrm{Hz}}$ |
| DC PERFORMANCE Input Offset Voltage Input Offset Voltage Drift Input Bias Current Input Bias Offset Current Open-Loop Gain | $\mathrm{T}_{\text {min }}$ to $\mathrm{T}_{\text {max, }}$ SOIC <br> $\mathrm{T}_{\text {min }}$ to $\mathrm{T}_{\text {max, }}$ LFCSP <br> $\mathrm{T}_{\text {min }}$ to $\mathrm{T}_{\text {max }}$, SOIC <br> $\mathrm{T}_{\text {min }}$ to $\mathrm{T}_{\text {max, }}$ LFCSP <br> $\mathrm{T}_{\text {min }}$ to $\mathrm{T}_{\text {max }}$ <br> $\mathrm{T}_{\text {min }}$ to $\mathrm{T}_{\text {max }}$ | 62 | 0.4 <br> 25 <br> 10 <br> 2 <br> 75 <br> 1 <br> 65 | $\begin{aligned} & 2 \\ & 6 \\ & 4 \\ & 80 \\ & 50 \\ & 20 \\ & 135 \\ & 10 \\ & 110 \end{aligned}$ | mV <br> mV <br> mV <br> $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ <br> $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ <br> pA <br> pA <br> pA <br> pA <br> dB |
| INPUT CHARACTERISTICS <br> Input Resistance Input Capacitance <br> Input Common-Mode Voltage Range Common-Mode Rejection | Common mode <br> Common mode <br> Differential mode $\begin{aligned} & \mathrm{V}_{\mathrm{CM}}= \pm 0.5 \mathrm{~V} \\ & \mathrm{~V}_{\mathrm{CM}}= \pm 0.5 \mathrm{~V}, \mathrm{~T}_{\mathrm{MIN}} \text { to } \mathrm{T}_{\mathrm{MAX}} \\ & \mathrm{~V}_{\mathrm{CM}}=-4.2 \mathrm{~V} \text { to } 2.2 \mathrm{~V}, \mathrm{~T}_{\mathrm{MIN}} \text { to } \mathrm{T}_{\mathrm{MAX}} \end{aligned}$ | $\begin{aligned} & -77 \\ & -73 \\ & -65 \\ & \hline \end{aligned}$ | $\begin{aligned} & 500 \\ & 1.3 \\ & 0.1 \\ & -V_{s} \text { to }\left(+V_{s}-2.8\right) \\ & -90 \end{aligned}$ |  | G $\Omega$ <br> pF <br> pF <br> V <br> dB <br> dB <br> dB |
| OUTPUT CHARACTERISTICS Output Overdrive Recovery Time | $\mathrm{V}_{\mathrm{IN}}= \pm 2.5 \mathrm{~V}, \mathrm{G}=2$ |  | 8 |  | ns |


| Parameter | Test Conditions/Comments | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Output Voltage Swing High <br> Low <br> Linear Output Current Short-Circuit Current | $R L=100 \Omega$ <br> $\mathrm{R}_{\mathrm{L}}=100 \Omega, \mathrm{~T}_{\text {MIN }}$ to $\mathrm{T}_{\text {max }}$ <br> $R_{L}=1 \mathrm{k} \Omega$ <br> $\mathrm{RL}_{\mathrm{L}}=1 \mathrm{k} \Omega$, $\mathrm{T}_{\text {min }}$ to $\mathrm{T}_{\text {max }}$ <br> $R \quad=100 \Omega$ <br> $\mathrm{R}_{\mathrm{L}}=100 \Omega, \mathrm{~T}_{\text {MIN }}$ to $\mathrm{T}_{\text {max }}$ <br> $R_{L}=1 \mathrm{k} \Omega$ <br> $\mathrm{RL}_{\mathrm{L}}=1 \mathrm{k} \Omega$, $\mathrm{T}_{\text {min }}$ to $\mathrm{T}_{\text {max }}$ <br> 1\% output error <br> Sinking <br> Sourcing | $\begin{aligned} & +V_{s}-1.5 \\ & +V_{s}-1.65 \\ & +V_{s}-1.1 \\ & +V_{s}-1.4 \end{aligned}$ | $\begin{aligned} & +V_{s}-1.3 \\ & +V_{s}-1 \\ & -V_{s}+1.4 \\ & -V_{s}+1 \\ & 40 \\ & 100 \\ & 170 \end{aligned}$ | $\begin{aligned} & -\mathrm{V}_{\mathrm{s}}+1.5 \\ & -\mathrm{V}_{\mathrm{s}}+1.65 \\ & -\mathrm{V}_{\mathrm{s}}+1.1 \\ & -\mathrm{V}_{\mathrm{s}}+1.2 \end{aligned}$ |  |
| POWER-DOWN <br> $\overline{\text { PD }}$ Pin Voltage <br> Turn On Time Turn Off Time Input Leakage Current | Enabled, $\mathrm{T}_{\text {min }}$ to $\mathrm{T}_{\text {max }}$ <br> Powered down, $\mathrm{T}_{\text {MIN }}$ to $\mathrm{T}_{\text {max }}$ $\begin{aligned} & \overline{P D}=+V_{s} \\ & \overline{P D}=-V_{s} \end{aligned}$ | >+V $\mathrm{V}_{\text {S }}-0.9$ | $\begin{aligned} & 0.3 \\ & 1 \\ & 0.3 \\ & 34 \end{aligned}$ | $<+V_{s}-3.5$ <br> 3 <br> 61 | V V <br> $\mu \mathrm{s}$ <br> $\mu \mathrm{s}$ <br> $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ |
| POWER SUPPLY <br> Operating Range Quiescent Current per Amplifier Powered Down Quiescent Current Positive Power Supply Rejection Negative Power Supply Rejection | $\begin{aligned} & +\mathrm{V}_{\mathrm{s}}=4.5 \mathrm{~V} \text { to } 5.5 \mathrm{~V},-\mathrm{V}_{\mathrm{s}}=-5 \mathrm{~V} \\ & +\mathrm{V}_{\mathrm{s}}=5 \mathrm{~V},-\mathrm{V}_{\mathrm{s}}=-4.5 \mathrm{~V} \text { to }-5.5 \mathrm{~V} \end{aligned}$ | 5 $\begin{aligned} & -67 \\ & -67 \end{aligned}$ | $\begin{aligned} & 19 \\ & 1.5 \\ & -72 \\ & -72 \end{aligned}$ | $\begin{aligned} & 10 \\ & 21 \\ & 3 \end{aligned}$ | $\begin{aligned} & \mathrm{mA} \\ & \mathrm{~mA} \\ & \mathrm{~dB} \\ & \mathrm{~dB} \end{aligned}$ |

## 5 V OPERATION

$\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C},+\mathrm{V}_{\mathrm{S}}=3 \mathrm{~V},-\mathrm{V}_{\mathrm{S}}=-2 \mathrm{~V}, \mathrm{G}=1, \mathrm{R}_{\mathrm{F}}=348 \Omega$ for $\mathrm{G}>1, \mathrm{R}_{\mathrm{L}}=100 \Omega$ to ground, unless otherwise noted.
Table 2.


| Parameter | Test Conditions/Comments | Min | Typ | Max | Unit |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Input Voltage Noise | $\mathrm{f}=100 \mathrm{kHz}$ |  | 4 |  | $\mathrm{nV} / \sqrt{ } \mathrm{Hz}$ |
| Input Current Noise | $\mathrm{f}=100 \mathrm{kHz}$ |  | 2.5 |  | $\mathrm{fA} / \sqrt{ } \mathrm{Hz}$ |
| DC PERFORMANCE |  |  |  |  |  |
| Input Offset Voltage |  |  | 0.5 | 2.3 | mV |
|  | $\mathrm{T}_{\text {min }}$ to $\mathrm{T}_{\text {max }}$, SOIC |  |  | 6.5 | mV |
|  | $\mathrm{T}_{\text {min }}$ to $\mathrm{T}_{\text {Max }}$, LFCSP |  |  | 5 | mV |
| Input Offset Voltage Drift | $\mathrm{T}_{\text {min }}$ to $\mathrm{T}_{\text {max }}$ SOIC |  | 25 | 75 | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
|  | Tmin to $\mathrm{T}_{\text {max }}$, LFCSP |  | 10 | 45 | $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ |
| Input Bias Current |  |  | 2 | 20 | pA |
|  | $\mathrm{T}_{\text {min }}$ to $\mathrm{T}_{\text {max }}$ |  | 50 | 70 | pA |
| Input Bias Offset Current |  |  | 1 | 10 | pA |
|  | $\mathrm{T}_{\text {MIN }}$ to $\mathrm{T}_{\text {max }}$ |  |  | 65 | pA |
| Open-Loop Gain |  | 61 | 63 |  | dB |
| INPUT CHARACTERISTICS |  |  |  |  |  |
| Input Resistance | Common mode |  | 500 |  | $\mathrm{G} \Omega$ |
| Input Capacitance | Common mode |  | 1.3 |  | pF |
|  | Differential mode |  | 0.1 |  | pF |
| Input Common-Mode Voltage Range Common-Mode Rejection |  |  | $-\mathrm{V}_{\mathrm{s}}$ to (+ $\left.\mathrm{V}_{\mathrm{s}}-2.9\right)$ |  | V |
|  | $\mathrm{V}_{\text {CM }}= \pm 0.25 \mathrm{~V}$ | -72 | -83 |  | dB |
|  | $\mathrm{V}_{\text {CM }}= \pm 0.3 \mathrm{~V}$, $\mathrm{T}_{\text {min }}$ to $\mathrm{T}_{\text {max }}$ | -70 |  |  | dB |
|  | $\mathrm{V}_{\text {CM }}= \pm 0.8 \mathrm{~V}$, $\mathrm{T}_{\text {MIN }}$ to $\mathrm{T}_{\text {MAX }}$ | -59 |  |  | dB |
| OUTPUT CHARACTERISTICS |  |  |  |  |  |
| Output Overdrive Recovery Time | $\mathrm{V}_{\mathrm{IN}}= \pm 1.25 \mathrm{~V}, \mathrm{G}=2$ |  | 13 |  | ns |
| Output Voltage Swing |  |  |  |  |  |
| High | $\mathrm{R}_{\mathrm{L}}=100 \Omega$ | $+\mathrm{V}_{\text {S }}-1.3$ | $+\mathrm{V}_{s}-1.2$ |  | V |
|  | $\mathrm{R}_{L}=100 \Omega, \mathrm{~T}_{\text {MIN }}$ to $\mathrm{T}_{\text {MAX }}$ | $+\mathrm{V}_{\text {s }}-1.4$ |  |  | V |
|  | $\mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$ | $+\mathrm{V}_{\text {s }}-1.1$ | $+\mathrm{V}_{\text {S }}-1$ |  | V |
|  | $\mathrm{RL}=1 \mathrm{k} \Omega$, $\mathrm{T}_{\text {Min }}$ to $\mathrm{T}_{\text {MAX }}$ | $+\mathrm{V}_{\mathrm{s}}-1.2$ |  |  | V |
| Low | $\mathrm{R}_{L}=100 \Omega$ |  | $-\mathrm{V}_{5}+1$ | $-\mathrm{V}_{s}+1.1$ | V |
|  | $\mathrm{RL}=100 \Omega, \mathrm{~T}_{\text {min }}$ to $\mathrm{T}_{\text {max }}$ |  |  | $-\mathrm{V}_{\mathrm{s}}+1.2$ | V |
|  | $\mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega$ |  | $-\mathrm{V}_{s}+0.9$ | $-V_{s}+1$ | V |
|  | $\mathrm{R}_{\mathrm{L}}=1 \mathrm{k} \Omega, \mathrm{T}_{\text {MIN }}$ to $\mathrm{T}_{\text {MAX }}$ |  |  | $-\mathrm{V}_{s}+1.1$ | V |
| Linear Output Current | 1\% output error |  | 20 |  | mA |
| Short-Circuit Current | Sinking |  | 40 |  | mA |
|  | Sourcing |  | 130 |  | mA |
| POWER-DOWN |  |  |  |  |  |
| $\overline{\text { PD Pin Voltage }}$ | Enabled, $\mathrm{T}_{\text {Min }}$ to $\mathrm{T}_{\text {Max }}$ | >+V $\mathrm{V}_{\text {S }}-0.9$ |  |  | V |
|  | Powered down, $\mathrm{T}_{\text {min }}$ to $\mathrm{T}_{\text {max }}$ |  |  | $<+V_{s}-3.5$ | V |
| Turn On Time |  |  | 0.2 |  | $\mu \mathrm{s}$ |
| Turn Off Time |  |  | 0.7 |  | $\mu \mathrm{s}$ |
| Input Leakage Current | $\overline{\mathrm{PD}}=+\mathrm{V}_{s}$ |  | 0.2 | 3 | $\mu \mathrm{A}$ |
|  | $\overline{\mathrm{PD}}=-\mathrm{V}_{\mathrm{s}}$ |  | 31 | 53 | $\mu \mathrm{A}$ |
| POWER SUPPLY |  |  |  |  |  |
| Operating Range |  | 5 |  | 10 | V |
| Quiescent Current per Amplifier |  |  | 14 | 16 | mA |
| Powered Down Quiescent Current |  |  | 1.5 | 2.8 | mA |
| Positive Power Supply Rejection | $+\mathrm{V}_{5}=4.75 \mathrm{~V}$ to $5.25 \mathrm{~V},-\mathrm{V}_{\mathrm{s}}=0 \mathrm{~V}$ | -66 | -71 |  | dB |
| Negative Power Supply Rejection | $+\mathrm{V}_{\mathrm{s}}=5 \mathrm{~V},-\mathrm{V}_{\mathrm{s}}=-0.25 \mathrm{~V}$ to +0.25 V | -63 | -69 |  | dB |

## ABSOLUTE MAXIMUM RATINGS

Table 3.

| Parameter | Rating |
| :--- | :--- |
| Supply Voltage | 10.6 V |
| Power Dissipation | See Figure 4 |
| Common-Mode Input Voltage Range | $-\mathrm{V}_{\mathrm{s}}-0.5 \mathrm{~V}$ to $+\mathrm{V}_{\mathrm{s}}+0.5 \mathrm{~V}$ |
| Differential Input Voltage | $\pm \mathrm{V}_{\mathrm{s}}$ |
| Storage Temperature Range | $-65^{\circ} \mathrm{C}$ to $+125^{\circ} \mathrm{C}$ |
| Operating Temperature Range | $-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ |
| Lead Temperature (Soldering, 10 sec$)$ | $300^{\circ} \mathrm{C}$ |
| Junction Temperature | $150^{\circ} \mathrm{C}$ |

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

## THERMAL RESISTANCE

Thermal performance is directly linked to PCB design and operating environment. Careful attention to PCB thermal design is required.

Table 4.

| Package Type | $\boldsymbol{\theta}_{\boldsymbol{J A}}$ | $\boldsymbol{\theta}_{\boldsymbol{\jmath} \boldsymbol{c}}$ | Unit |
| :--- | :--- | :--- | :--- |
| CP-8-13 | 94 | 29 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| RD-8-1 | 79 | 29 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |
| CP-16-20 | 64 | 14 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

## MAXIMUM SAFE POWER DISSIPATION

The maximum safe power dissipation for the ADA4817-1/ ADA4817-2 is limited by the associated rise in junction temperature $\left(\mathrm{T}_{\mathrm{J}}\right)$ on the die. At approximately $150^{\circ} \mathrm{C}$ (which is the glass transition temperature), the properties of the plastic change. Even temporarily exceeding this temperature limit may change the stresses that the package exerts on the die, permanently shifting the parametric performance of the ADA4817-1/
ADA4817-2. Exceeding a junction temperature of $150^{\circ} \mathrm{C}$ for an extended period can result in changes in silicon devices, potentially causing degradation or loss of functionality.
The power dissipated in the package $\left(\mathrm{P}_{\mathrm{D}}\right)$ is the sum of the quiescent power dissipation and the power dissipated in the die due to the ADA4817-1/ADA4817-2 drive at the output. The quiescent power is the voltage between the supply pins ( $\mathrm{V}_{\mathrm{s}}$ ) multiplied by the quiescent current ( $\mathrm{I}_{\mathrm{s}}$ ).

$$
\begin{equation*}
P_{D}=\text { Quiescent Power }+(\text { Total Drive Power }- \text { Load Power }) \tag{1}
\end{equation*}
$$

$$
\begin{equation*}
P_{D}=\left(V_{S} \times I_{S}\right)+\left(\frac{V_{S}}{2} \times \frac{V_{O U T}}{R_{L}}\right)-\frac{V_{O U T}^{2}}{R_{L}} \tag{2}
\end{equation*}
$$

Consider root mean square (rms) output voltages. If $\mathrm{R}_{\mathrm{L}}$ is referenced to $-V_{s}$, as in single-supply operation, the total drive power is $\mathrm{V}_{\mathrm{s}} \times$ Iout. If the rms signal levels are indeterminate, consider the worst-case scenario, when $V_{\text {out }}=V_{S} / 4$ for $R_{L}$ to midsupply.

$$
\begin{equation*}
P_{D}=\left(V_{S} \times I_{S}\right)+\frac{\left(V_{S} / 4\right)^{2}}{R_{L}} \tag{3}
\end{equation*}
$$

In single-supply operation with $R_{L}$ referenced to $-V_{S}$, the worstcase situation is $V_{\text {out }}=V_{s} / 2$.

Airflow increases heat dissipation, effectively reducing $\theta_{\text {JA }}$. More metal directly in contact with the package leads and exposed pad from metal traces, through holes, ground, and power planes also reduces $\theta_{\mathrm{IA}}$.

Figure 4 shows the maximum safe power dissipation in the package vs. the ambient temperature for the exposed paddle 8-lead LFCSP (single $94^{\circ} \mathrm{C} / \mathrm{W}$ ), 8-lead SOIC (single $79^{\circ} \mathrm{C} / \mathrm{W}$ ), and 16 -lead LFCSP (dual $64^{\circ} \mathrm{C} / \mathrm{W}$ ) packages on JEDEC standard 4-layer boards. $\theta_{\mathrm{JA}}$ values are approximations.


Figure 4. Maximum Safe Power Dissipation vs. Ambient Temperature for a 4-Layer Board

## ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

## PIN CONFIGURATIONS AND FUNCTION DESCRIPTIONS



## NOTES

1. NIC = NO INTERNAL CONNECTION.
2. EXPOSED PAD. CAN BE CONNECTED TO GND, - $\mathrm{V}_{\mathrm{S}}$ PLANE, OR LEFT FLOATING.

Figure 5. ADA4817-1 Pin Configuration (8-Lead LFCSP)
Table 5. ADA4817-1 Pin Function Descriptions (8-Lead LFCSP)

| Pin No. | Mnemonic | Description |
| :--- | :--- | :--- |
| 1 | $\overline{\mathrm{PD}}$ | Power-Down. Do not leave floating. |
| 2 | FB | Feedback Pin. |
| 3 | -IN | Inverting Input. |
| 4 | + IN | Noninverting Input. |
| 5 | $-\mathrm{V}_{\mathrm{S}}$ | Negative Supply. |
| 6 | NIC | No Internal Connection. |
| 7 | OUT | Output. |
| 8 | $+V_{S}$ | Positive Supply. |
|  | EPAD | Exposed Pad. Can be connected to GND, $-V_{s}$ plane, or left floating. |



NOTES

1. NIC $=$ NO INTERNAL CONNECTION.
2. EXPOSED PAD. CAN BE CONNECTED TO GND,
$\mathbf{- V}_{\mathrm{S}}$ PLANE, OR LEFT FLOATING.
Figure 6. ADA4817-1 Pin Configuration (8-Lead SOIC)
Table 6. ADA4817-1 Pin Function Descriptions (8-Lead SOIC)

| Pin No. | Mnemonic | Description |
| :--- | :--- | :--- |
| 1 | FB | Feedback Pin. |
| 2 | - IN | Inverting Input. |
| 3 | + IN | Noninverting Input. |
| 4 | $-V_{S}$ | Negative Supply. |
| 5 | NIC | No Internal Connection. |
| 6 | OUT | Output. |
| 7 | $+\mathrm{V}_{\mathrm{S}}$ | Positive Supply. |
| 8 | PD | Power-Down. Do not leave floating. |
|  | EPAD | Exposed Pad. Can be connected to GND, $-\mathrm{V}_{\mathrm{S}}$ plane, or left floating. |



## NOTES

1. NIC = NO INTERNAL CONNECTION.
2. EXPOSED PAD. CAN BE CONNECTED

TO GND, - $V_{\mathrm{S}}$ PLANE, OR LEFT FLOATING.
Figure 7. ADA4817-2 Pin Configuration (16-Lead LFCSP)
Table 7. ADA4817-2 Pin Function Descriptions (16-Lead LFCSP)

| Pin No. | Mnemonic | Description |
| :--- | :--- | :--- |
| 1 | - IN1 | Inverting Input 1. |
| 2 | + IN1 | Noninverting Input 1. |
| 3,11 | NIC | No Internal Connection. |
| 4 | $-V_{s 2}$ | Negative Supply 2. |
| 5 | OUT2 | Output 2. |
| 6 | $+V_{s 2}$ | Positive Supply 2. |
| 7 | $\frac{\text { PD2 }}{}$ | Power-Down 2. Do not leave floating. |
| 8 | FB2 | Feedback Pin 2. |
| 9 | - IN2 | Inverting Input 2. |
| 10 | + IN2 | Noninverting Input 2. |
| 12 | $-V_{s 1}$ | Negative Supply 1. |
| 13 | OUT1 | Output 1. |
| 14 | $+V_{s 1}$ | Positive Supply 1. |
| 15 | PD1 | Power-Down 1. Do not leave floating. |
| 16 | FB1 | Feedback Pin 1. |
|  | EPAD | Exposed Pad. Can be connected to GND, $-V_{s}$ plane, or left floating. |

## TYPICAL PERFORMANCE CHARACTERISTICS

$\mathrm{T}_{\mathrm{A}}=25^{\circ} \mathrm{C}, \mathrm{V}_{\mathrm{S}}= \pm 5 \mathrm{~V}, \mathrm{G}=1,\left(\mathrm{R}_{\mathrm{F}}=348 \Omega\right.$ for $\left.\mathrm{G}>1\right), \mathrm{R}_{\mathrm{L}}=100 \Omega$ to ground, small signal $\mathrm{V}_{\text {out }}=100 \mathrm{mV}$ p-p, large signal $\mathrm{V}_{\text {out }}=2 \mathrm{~V} \mathrm{p}-\mathrm{p}$, unless otherwise noted.


Figure 8. Small Signal Frequency Response for Various Gains (LFCSP)


Figure 9. Small Signal Frequency Response for Various Supplies


Figure 10. Small Signal Frequency Response for Various $C_{L}$


Figure 11. Large Signal Frequency Response for Various Gains


Figure 12. Large Signal Frequency Response for Various Supplies


Figure 13. Small Signal Frequency Response for Various $R_{F}$


Figure 14. 0.1 dB Flatness Frequency Response vs. Gain and Output Voltage


Figure 15. Distortion vs. Frequency for Various Loads, Vout $=2 \mathrm{Vp}-\mathrm{p}$


Figure 16. Distortion vs. Frequency for Various Supplies, $G=2, ~ V$ out $=2 \mathrm{Vp}-p$


Figure 17. Small Signal Frequency Response vs. Temperature


Figure 18. Distortion vs. Frequency for Various Supplies, V


Figure 19. Distortion vs. Output Voltage for Various Loads


Figure 20. Small Signal Transient Response vs. Package


Figure 21. Output Overdrive Recovery


Figure 22. Small Signal Transient Response


TIME (5ns/DIV)
Figure 23. Large Signal Transient Response vs. Package


TIME (5ns/DIV)
Figure 24. 0.1\% Short-Term Settling Time


Figure 25. Power Supply Rejection Ratio (PSRR) vs. Frequency


Figure 26. Common-Mode Rejection Ratio (CMRR) vs. Frequency


Figure 27. Output Impedance vs. Frequency


Figure 28. Input Voltage Noise vs. Frequency


Figure 29. Quiescent Current vs. Temperature for Various Supply Voltages


Figure 30. Output Saturation Voltage vs. Temperature


Figure 31. Open-Loop Gain and Phase vs. Frequency


Figure 32. Input Offset Voltage Histogram
( $V_{s}= \pm 5$ V), LFCSP Only


Figure 33. Input Offset Voltage Histogram over Temperature ( $V_{s}= \pm 5$ V), LFCSP Only


Figure 34. Input Offset Voltage Histogram over Temperature $\left(V_{s}= \pm 5 \mathrm{~V}\right)$, SOIC Only


Figure 35. Input Offset Voltage Histogram $\left(V_{s}= \pm 5 \mathrm{~V}\right)$, SOIC Only


Figure 36. Input Offset Voltage Histogram over Temperature ( $V_{s}=5$ V), LFCSP Only


Figure 37. Input Offset Voltage Histogram over Temperature ( $V_{S}=5 \mathrm{~V}$ ), SOIC Only


Figure 38. Offset Voltage vs. Temperature $\left(V_{S}= \pm 5 \mathrm{~V}\right)$


Figure 39. Input Offset Voltage Drift Histogram $\left(V_{s}= \pm 5 \mathrm{~V}\right)$


Figure 40. Input Bias Current Histogram over Temperature
$\left(V_{s}= \pm 5 \mathrm{~V}\right)$


Figure 41. Offset Voltage vs. Temperature $\left(V_{s}=5 \mathrm{~V}\right)$


INPUT OFFSET VOLTAGE DRIFT ( $\mu \mathrm{V} /{ }^{\circ} \mathrm{C}$ )
Figure 42. Input Offset Voltage Drift Histogram ( $V_{S}=5 \mathrm{~V}$ )


Figure 43. Input Bias Current Histogram over Temperature
( $V_{s}=5 \mathrm{~V}$ )


Figure 44. Common-Mode Rejection vs. Common-Mode Voltage, $V_{s}= \pm 5 \mathrm{~V}$


Figure 45. Common-Mode Rejection vs. Common-Mode Voltage, $V_{s}=5 \mathrm{~V}$

## ADA4817-1/ADA4817-2

## TEST CIRCUITS

The output feedback pins are used for ease of layout as shown in Figure 46 to Figure 51.


Figure 46. $G=1$ Configuration


Figure 47. Positive Power Supply Rejection


Figure 48. Capacitive Load Configuration


Figure 49. Noninverting Gain Configuration


Figure 50. Negative Power Supply Rejection


Figure 51. Common-Mode Rejection

## THEORY OF OPERATION

The ADA4817-1/ADA4817-2 are voltage feedback operational amplifiers that combine new architecture for FET input operational amplifiers with the eXFCB process from Analog Devices, resulting in an outstanding combination of speed and low noise. The innovative high speed FET input stage handles commonmode signals from the negative supply to within 2.7 V of the positive rail. This stage is combined with an H -bridge to attain an $870 \mathrm{~V} / \mu$ s slew rate and low distortion, in addition to $4 \mathrm{nV} / \sqrt{ } \mathrm{Hz}$ input voltage noise. The amplifier features a high speed output stage capable of driving heavy loads sourcing and sinking up to 40 mA of linear current. Supply current and offset current are laser trimmed for optimum performance. These specifications make the ADA4817-1/ADA4817-2 a great choice for high speed instrumentation and high resolution data acquisition systems. Their low noise, picoampere input current, precision offset, and high speed make them superb preamps for fast photo-diode applications.

## CLOSED-LOOP FREQUENCY RESPONSE

The ADA4817-1/ADA4817-2 are classic voltage feedback amplifiers with an open-loop frequency response that can be approximated as the integrator response shown in Figure 54. Basic closed-loop frequency response for inverting and noninverting configurations can be derived from the schematics shown in Figure 52 and Figure 53.


Figure 52. Noninverting Configuration


Figure 53. Inverting Configuration

## NONINVERTING CLOSED-LOOP FREQUENCY RESPONSE

Solving for the transfer function,

$$
\begin{equation*}
\frac{V_{O}}{V_{I}}=\frac{2 \pi \times f_{\text {CROSSOVER }}\left(R_{G}+R_{F}\right)}{\left(R_{F}+R_{G}\right) S+2 \pi \times f_{\text {CROSSOVER }} \times R_{G}} \tag{4}
\end{equation*}
$$

where:
$f_{\text {CROSSOVER }}$ is the frequency where the open-loop gain of the amplifier equals 0 dB .
$V_{O}$ is the output voltage.
$V_{I}$ is the input voltage.

At dc,

$$
\begin{equation*}
\frac{V_{O}}{V_{I}}=\frac{R_{F}+R_{G}}{R_{G}} \tag{5}
\end{equation*}
$$

The closed-loop -3 dB frequency is

$$
\begin{equation*}
f_{-3 d B}=f_{\text {CROSSOVER }} \times \frac{R_{G}}{R_{F}+R_{G}} \tag{6}
\end{equation*}
$$

## INVERTING CLOSED-LOOP FREQUENCY RESPONSE

Solving for the transfer function,

$$
\begin{equation*}
\frac{V_{O}}{V_{I}}=\frac{-2 \pi \times f_{\text {CROSSOVER }} \times R_{F}}{\left(R_{F}+R_{G}\right) S+2 \pi \times f_{\text {CROSSOVER }} \times R_{G}} \tag{7}
\end{equation*}
$$

At dc
$\frac{V_{O}}{V_{I}}=-\frac{R_{F}}{R_{G}}$
Solve for closed-loop -3 dB frequency by

$$
\begin{equation*}
f_{-3 d B}=f_{\text {CROSSOVER }} \times \frac{R_{G}}{R_{F}+R_{G}} \tag{9}
\end{equation*}
$$



Figure 54. Open-Loop Gain vs. Frequency
The closed-loop bandwidth is inversely proportional to the noise gain of the op amp circuit, $\left(\mathrm{R}_{\mathrm{F}}+\mathrm{R}_{\mathrm{G}}\right) / \mathrm{R}_{\mathrm{G}}$. This simple model is accurate for noise gains above 2 . The actual bandwidth of circuits with noise gains at or below 2 is higher than those predicted with this model due to the influence of other poles in the frequency response of the real op amp.
Figure 55 shows the dc errors of the voltage feedback amplifier. For both inverting and noninverting configurations,

$$
\begin{align*}
& V_{\text {OUT }} \text { (error) }= \\
& I_{b+} \times R_{S}\left(\frac{R_{G}+R_{F}}{R_{G}}\right)-I_{b-} \times R_{F}+V_{O S}\left(\frac{R_{G}+R_{F}}{R_{G}}\right) \tag{10}
\end{align*}
$$

where $I_{b}$ is the bias current.


Figure 55. DC Errors of the Voltage Feedback Amplifier
The voltage error due to $\mathrm{I}_{\mathrm{b}+}$ and $\mathrm{I}_{\mathrm{b}-}$ is minimized if $\mathrm{R}_{\mathrm{S}}=\mathrm{R}_{\mathrm{F}} \| \mathrm{R}_{\mathrm{G}}$ (though with the ADA4817-1/ADA4817-2 input currents in the picoamp range, this is likely not a concern). To include commonmode effects and power supply rejection effects, total Vos can be modeled by

$$
\begin{equation*}
V_{O S}=V_{O S n o m}+\frac{\Delta V_{S}}{P S R}+\frac{\Delta V_{C M}}{C M R} \tag{11}
\end{equation*}
$$

where:
Vos is the offset voltage.
$V_{O S_{n o m}}$ is the offset voltage specified at nominal conditions.
$\Delta V_{S}$ is the change in power supply from nominal conditions.
$P S R$ is the power supply rejection.
$\Delta V_{C M}$ is the change in common-mode voltage from nominal conditions.
$C M R$ is the common-mode rejection.

## WIDEBAND OPERATION

The ADA4817-1/ADA4817-2 provides excellent performance as a high speed buffer. Figure 52 shows the circuit used for wideband characterization for high gains. The impedance at the summing junction $\left(R_{F} \| R_{G}\right)$ forms a pole in the loop response of the amplifier with the input capacitance of the amplifier of 1.3 pF . This pole can cause peaking and ringing if its frequency is too low. Feedback resistances of $100 \Omega$ to $400 \Omega$ are recommended because they minimize the peaking and they do not degrade the performance of the output stage. Peaking in the frequency response can also be compensated for with a small feedback capacitor $\left(\mathrm{C}_{\mathrm{F}}\right)$ in parallel with the feedback resistor, or a series resistor in the noninverting input, as shown in Figure 56.

The distortion performance depends on the following variables:

- The closed-loop gain of the application
- Whether it is inverting or noninverting
- Amplifier loading
- Signal frequency and amplitude
- Board layout

The best performance is usually obtained in the G + 1 configuration with no feedback resistance, big output load resistors, and small board parasitic capacitances.

## DRIVING CAPACITIVE LOADS

In general, high speed amplifiers have a difficult time driving capacitive loads. This is particularly true in low closed-loop gains, where the phase margin is the lowest.
The difficulty arises because the load capacitance, $\mathrm{C}_{\mathrm{t}}$, forms a pole with the output resistance, $\mathrm{R}_{\mathrm{O}}$, of the amplifier. The pole can be described by the following equation:

$$
\begin{equation*}
f_{P}=\frac{1}{2 \pi R_{O} C_{L}} \tag{12}
\end{equation*}
$$

If this pole occurs too close to the unity-gain crossover point, the phase margin degrades. Degradation is due to the additional phase loss associated with the pole.
Note that such capacitance introduces significant peaking in the frequency response. Larger capacitance values can be driven but must use a small series resistor, $\mathrm{R}_{\mathrm{SNUB}}$, at the output of the amplifier, as shown in Figure 56. Adding $\mathrm{R}_{\mathrm{SNUB}}$ creates a zero that cancels the pole introduced by the load capacitance. Typical values for
 the circuit requirements. Figure 56 also shows another way to reduce the effect of the pole created by the capacitive load $\left(\mathrm{C}_{\mathrm{L}}\right)$ by placing a capacitor $\left(\mathrm{C}_{\mathrm{F}}\right)$ in the feedback loop parallel to the feedback resistor Typical capacitor values can range from 0.5 pF to 2 pF . Figure 59 shows the effect of adding a feedback capacitor to the frequency response.


Figure 56. RsNUB or $C_{F}$ Used to Reduce Peaking

## THERMAL CONSIDERATIONS

With 10 V power supplies and 19 mA quiescent current, the ADA4817-1/ADA4817-2 dissipate 190 mW with no load. This implies that with the thermal resistances listed in Table 4, the junction temperature is typically almost $25^{\circ} \mathrm{C}$ higher than the ambient temperature. The ADA4817-1/ADA4817-2 can maintain a constant bandwidth over temperature; therefore, an initial ramp up of the current consumption during warm-up is expected. Vos can change up to 0.3 mV due to warm-up effects for an ADA4817-1/ADA4817-2 on $\pm 5 \mathrm{~V}$. The input bias current typically increases by a factor of 1.7 for every $10^{\circ} \mathrm{C}$ rise in temperature.

Heavy loads increase power dissipation and raise the chip junction temperature as described in the Absolute Maximum Ratings section. Take care not to exceed the rated power dissipation of the package.

## POWER-DOWN OPERATION

The ADA4817-1/ADA4817-2 are equipped with separate powerdown pins (PD) for each amplifier that allow the user the ability to reduce the quiescent supply current when an amplifier is inactive from 19 mA to below 2 mA . The power-down threshold levels are referenced to the $+V_{s}$ pin. The amplifier is enabled when the $\overline{\mathrm{PD}}$ pin voltage is within 0.9 V of the $+\mathrm{V}_{\mathrm{s}}$ supply. The amplifier is disabled when the $\overline{\mathrm{PD}}$ pin voltage is at least 3.5 V from the $+\mathrm{V}_{\mathrm{S}}$ supply. Table 8 shows the required thresholds for power-down with supplies of $\pm 5 \mathrm{~V}$ and $3 \mathrm{~V},-2 \mathrm{~V}$, over temperature. If the $\overline{\mathrm{PD}}$ pin is not used, connect it to the positive power supply to ensure proper startup.

Table 8. $\overline{\text { PD }}$ Pin Control

| Supply Voltages | $\mathbf{+ 5} \mathbf{V}$ | $\mathbf{+ 3} \mathbf{V ,} \mathbf{- 2 ~ V}$ |
| :--- | :--- | :--- |
| Amplifier Enabled | $>4.1 \mathrm{~V}$ | $>2.1 \mathrm{~V}$ |
| Amplifier Disabled | $<1.5 \mathrm{~V}$ | $<-0.5 \mathrm{~V}$ |

When the amplifier is powered down with the supplies of +3 V and -2 V , the $\overline{\mathrm{PD}}$ pin needs to be driven below ground to ensure the power-down. This may be a problem if a microcontroller is being used to drive the PD pin. The circuit in Figure 57 can be added to ensure that the required threshold is met.


Figure 57. Power-Down Circuit
The plot in Figure 58 shows that the $\overline{\mathrm{PD}}$ pin is driven to the positive rail when the microcontroller logic is high, and to the negative rail when the microcontroller logic is low. The RF5 and RF6 resistors must be chosen to be sufficiently high so that minimal current is drawn by the circuit.


Figure 58. Power-Down Operation

## CAPACITIVE FEEDBACK

Due to package variations and pin to pin parasitics between the single and the dual models, the ADA4817-2 has a little more peaking than the ADA4817-1, especially at a gain of 2 . The recommended method to tame the peaking is to place a feedback capacitor across the feedback resistor. Figure 59 shows the small signal frequency response of the ADA4817-2 at a gain of 2 vs. $\mathrm{C}_{\mathrm{F}}$. At first, no $\mathrm{C}_{\mathrm{F}}$ was used to show the peaking; but then two other values of 0.5 pF and 1 pF were used to show how to reduce the peaking or even eliminate it. If the power consumption is a factor in the system, using a larger feedback capacitor is acceptable as long as a feedback capacitor is used across it to control the peaking, as shown in Figure 59.
However, if power consumption is not an issue, a lower value feedback resistor, such as $200 \Omega$, does not require any additional feedback capacitance to maintain flatness and lower peaking.


Figure 59. Small Signal Frequency Response vs. Feedback Capacitor (ADA4817-2)

## HIGHER FREQUENCY ATTENUATION

There is another package variation problem between the SOIC and the LFCSP package. The SOIC package shows approximately 1 dB to 1.5 dB of additional peaking at a gain of 1 , due to the parasitic capacitances in the SOIC package, which is not recommended for very high frequency parts that exceed 1 GHz . A good approach to reduce the peaking is to place a resistor, $\mathrm{R}_{\mathrm{s}}$, in series with the noninverting input, which creates a first-order pole formed by $\mathrm{Rs}_{\mathrm{s}}$ and $\mathrm{C}_{\mathrm{IN}}$, the common-mode input capacitance.

Figure 60 shows the higher frequency attenuation, which reduces the peaking but also reduces the -3 dB bandwidth.


Figure 60. Small Signal Frequency Response for Various Rs (SOIC)
As shown in Figure 60, the peaking dropped by almost 2 dB when $\mathrm{R}_{\mathrm{S}}=0 \Omega$ to $\mathrm{R}_{\mathrm{S}}=100 \Omega$, and in return, the -3 dB bandwidth dropped from 1 GHz to 700 MHz . To maintain the -3 dB bandwidth and to reduce peaking, an RLC circuit is recommended instead of $\mathrm{R}_{\mathrm{s}}$, as shown in Figure 61.


The R in parallel to the series LC forms a notch that can be shaped to compensate for the peaking produced by the amplifier. The result is a smooth $1 \mathrm{GHz}-3 \mathrm{~dB}$ bandwidth, 250 MHz 0.1 dB flatness, and less than 1 dB of peaking. Place this circuit in the path of the noninverting input when the ADA4817-1/ADA4817-2 are used at a gain of 1 . The RLC values may need adjustment depending on the source impedance and the flatness and bandwidth required. Figure 62 shows the frequency response after the RLC circuit is in place.


Figure 62. Frequency Response with RLC Circuit

## LAYOUT, GROUNDING, AND BYPASSING CONSIDERATIONS

Laying out the PCB is usually the last step in the design process and often proves to be one of the most critical. A good design can be rendered useless because of poor layout. Because the ADA4817-1/ADA4817-2 can operate into the radio frequency (RF) spectrum, high frequency board layout considerations must be taken into account. The PCB layout, signal routing, power supply bypassing, and grounding all must be addressed to ensure optimal performance.

## SIGNAL ROUTING

The ADA4817-1/ADA4817-2 feature a low distortion pinout with a dedicated feedback pin that allows a compact layout. The dedicated feedback pin reduces the distance from the output to the inverting input, which greatly simplifies the routing of the feedback network.

When laying out the ADA4817-1/ADA4817-2 as a unity-gain amplifier, it is recommended to place a short but wide trace between the dedicated feedback pins and the inverting input to the amplifier to minimize stray parasitic inductance.
To minimize parasitic inductances, use ground planes under high frequency signal traces. However, remove the ground plane from under the input and output pins to minimize the formation of parasitic capacitors, which degrades phase margin. Run signals are susceptible to noise pickup on the internal layers of the PCB, which can provide maximum shielding.

## POWER SUPPLY BYPASSING

Power supply bypassing is a critical aspect of the PCB design process. For best performance, properly bypass the ADA4817-1/ ADA4817-2 power supply pins.

A parallel connection of capacitors from each of the power supply pins to ground works best. Paralleling different values and sizes of capacitors helps ensure that the power supply pins see a low ac impedance across a wide band of frequencies, which is important for minimizing the coupling of noise into the amplifier. Starting directly at the power supply pins, place the smallest value and sized component on the same side of the board as the amplifier, and as close as possible to the amplifier, and connect it to the ground plane. Repeat this process for the next largest value capacitor. It is recommended to use a $0.1 \mu \mathrm{~F}$ ceramic, 0508 case for the ADA4817-1/ADA4817-2.

The 0508 case offers low series inductance and excellent high frequency performance. The $0.1 \mu \mathrm{~F}$ provides low impedance at high frequencies. Place a $10 \mu \mathrm{~F}$ electrolytic capacitor in parallel with the $0.1 \mu \mathrm{~F}$. The $10 \mu \mathrm{~F}$ electrolytic capacitor provides low ac impedance at low frequencies. Smaller values of electrolytic capacitors can be used depending on the circuit requirements. Additional smaller value capacitors help provide a low
impedance path for unwanted noise out to higher frequencies but are not always necessary.

Placement of the capacitor returns (grounds) is also important. Returning the grounds of the capacitor close to the amplifier load is critical for distortion performance. Keeping the distance of the capacitors short, but equal from the load, is optimal for performance.

In some cases, bypassing between the two supplies can help to improve PSRR and to maintain distortion performance in crowded or difficult layouts. Bypassing is another option to improve performance.

Minimizing the trace length and widening the trace from the capacitors to the amplifier reduces the trace inductance. A series inductance with the parallel capacitance can form a tank circuit, which can introduce high frequency ringing at the output. This additional inductance can also contribute to increased distortion due to high frequency compression at the output. Minimize the use of vias in the direct path to the amplifier power supply pins because vias can introduce parasitic inductance, which can lead to instability. When required to use vias, choose multiple large diameter vias because this lowers the equivalent parasitic inductance.

## GROUNDING

The use of ground and power planes is encouraged as a method of providing low impedance returns for power supply and signal currents. Ground and power planes can also help to reduce stray trace inductance and to provide a low thermal path for the amplifier. Do not use ground and power planes under any of the pins. The mounting pads and the ground or power planes can form a parasitic capacitance at the input of the amplifier. Stray capacitance on the inverting input and the feedback resistor form a pole, which degrades the phase margin, leading to instability. Excessive stray capacitance on the output also forms a pole, which degrades phase margin.

## EXPOSED PAD

The ADA4817-1/ADA4817-2 feature an exposed pad, which lowers the thermal resistance by $25 \%$ compared to a standard SOIC plastic package. The exposed pad of the ADA4817-1/ ADA4817-2 floats internally, which provides the maximum flexibility and ease of use. It can be connected to the ground plane or to the negative power supply plane. In cases where thermal heating is not an issue, the exposed pad can be left floating.

The use of thermal vias or heat pipes can also be incorporated into the design of the mounting pad for the exposed pad. These additional vias help to lower the overall junction to ambient temperature $\left(\theta_{\text {JA }}\right)$. Using a heavier weight copper on the surface to which the exposed paddle of the amplifier is soldered can
greatly reduce the overall thermal resistance seen by the ADA4817-1/ADA4817-2.

## LEAKAGE CURRENTS

Poor PCB layout, contaminants, and the board insulator material can create leakage currents that are much larger than the input bias current of the ADA4817-1/ADA4817-2. Any voltage differential between the inputs and nearby runs sets up leakage currents through the PCB insulator, for example, $1 \mathrm{~V} /$ $100 \mathrm{G} \Omega=10 \mathrm{pA}$. Similarly, any contaminants, such as skin oils on the board, can create significant leakage. To reduce leakage significantly, put a guard ring (shield) around the inputs and input leads that are driven to the same voltage potential as the inputs. This way there is no voltage potential between the inputs and surrounding area to set up any leakage currents. For the guard ring to be completely effective, it must be driven by a relatively low impedance source and it must completely surround the input leads on all sides (above and below) when using a multilayer board.

Another effect that can cause leakage currents is the charge absorption of the insulator material itself. Minimizing the amount of material between the input leads and the guard ring helps to reduce the absorption. In addition, low absorption materials, such as Teflon ${ }^{\star}$ or ceramic, can be necessary in some instances.

## INPUT CAPACITANCE

Along with bypassing and ground, high speed amplifiers can be sensitive to parasitic capacitance between the inputs and ground. A few picofarads of capacitance reduces the input impedance at high frequencies, in turn increasing the gain of the amplifier, causing peaking of the frequency response or even oscillations if severe enough. It is recommended to place the external passive components connected to the input pins as close as possible to the inputs to avoid parasitic capacitance. The ground and power planes must be kept at a small distance from the input pins on all layers of the board.

## INPUT-TO-INPUT/OUTPUT COUPLING

To minimize capacitive coupling between the inputs and outputs, ensure that the output signal traces are not parallel with the inputs. In addition, ensure that the input traces are not close to each other. A minimum of 7 mils between the two inputs is recommended.

## APPLICATIONS INFORMATION

## LOW DISTORTION PINOUT

The ADA4817-1/ADA4817-2 feature a low distortion pinout from Analog Devices. The new pinout provides two advantages over the traditional pinout. The first advantage is improved second harmonic distortion performance, which is accomplished by the physical separation of the noninverting input pin and the negative power supply pin. The second advantage is the simplification of the layout due to the dedicated feedback pin and easy routing of the gain set resistor back to the inverting input pin. This pinout allows a compact layout, which helps to minimize parasitics and increase stability.
The designer does not need to use the dedicated feedback pin to provide feedback for the ADA4817-1/ADA4817-2. The output pin of the ADA4817-1/ADA4817-2 can still be used to provide feedback to the inverting input of the ADA4817-1/ADA4817-2.

## WIDEBAND PHOTODIODE PREAMP

The wide bandwidth and low noise of the ADA4817-1/ ADA4817-2 make it an ideal choice for transimpedance amplifiers, such as those used for signal conditioning with high speed photodiodes. Figure 63 shows a current to voltage converter with an electrical model of a photodiode. The basic transfer function is

$$
\begin{equation*}
V_{\text {OUT }}=\frac{I_{\text {PНОтО }} \times R_{F}}{1+s C_{F} R_{F}} \tag{13}
\end{equation*}
$$

where:
$I_{\text {Рното }}$ is the output current of the photodiode.
$R_{F}$ and $C_{F}$ are the parallel combination that sets the signal bandwidth.


Figure 63. Wideband Photodiode Preamp

The stable bandwidth attainable with this preamp is a function of $\mathrm{R}_{\mathrm{F}}$, the gain bandwidth product of the amplifier, and the total capacitance at the summing junction of the amplifier, including the photodiode capacitance $\left(\mathrm{C}_{S}\right)$ and the amplifier input capacitance. $\mathrm{R}_{\mathrm{F}}$ and the total capacitance produce a pole in the loop transmission of the amplifier that can result in peaking and instability. Adding $C_{F}$ creates a zero in the loop transmission that compensates for the effect of the pole and reduces the signal bandwidth. It can be shown that the signal bandwidth obtained with a $45^{\circ}$ phase margin $\left(\mathrm{f}_{(45)}\right)$ is defined by

$$
\begin{equation*}
f_{(45)}=\sqrt{\frac{f_{C R}}{2 \pi \times R_{F} \times\left(C_{S}+C_{M}+C_{D}\right)}} \tag{14}
\end{equation*}
$$

where:
$f_{C R}$ is the amplifier crossover frequency.
$R_{F}$ is the feedback resistor.
$C_{S}$ is the source capacitance including the photodiode and the board parasitic.
$C_{M}$ is the common-mode capacitance of the amplifier.
$C_{D}$ is the differential capacitance of the amplifier.
The $C_{F}$ value that produces $f_{(45)}$ is shown to be

$$
\begin{equation*}
C_{F}=\sqrt{\frac{C_{S}+C_{M}+C_{D}}{2 \pi \times R_{F} \times f_{C R}}} \tag{15}
\end{equation*}
$$

The frequency response shows less peaking if larger $C_{F}$ values are used.
Figure 64 shows the preamplifier output noise over frequency.


Figure 64. Photodiode Voltage Noise Contributions


Figure 65. Photodiode Preamp Frequency Response
The pole in the loop transmission translates to a zero in the noise gain of the amplifier, leading to an amplification of the input voltage noise over frequency.

The loop transmission zero introduced by $\mathrm{C}_{\mathrm{F}}$ limits the amplification. The noise gain bandwidth extends past the preamp signal bandwidth and is eventually rolled off by the decreasing loop gain of the amplifier. The current equivalent noise from the inverting terminal is typically negligible for most applications. The innovative architecture used in the ADA4817-1/ADA4817-2 makes balancing both inputs unnecessary, as opposed to traditional FET input amplifiers. Therefore, minimizing the impedance seen from the noninverting terminal to ground at all frequencies is critical for optimal noise performance.

Integrating the square of the output voltage noise spectral density over frequency and then taking the square root allows the user to obtain the total rms output noise of the preamp. Table 9 summarizes approximations for the amplifier and feedback and source resistances. Noise components for an example preamp with $\mathrm{R}_{\mathrm{F}}=50 \mathrm{k} \Omega, \mathrm{Cs}=30 \mathrm{pF}$, and $\mathrm{C}_{\mathrm{F}}=0.5 \mathrm{pF}$ (bandwidth of about 6.4 MHz ) are also listed. VEN is the equivalent voltage noise and IEN is the equivalent current noise.

Table 9. RMS Noise Contributions of Photodiode Preamp

| Contributor | Expression | RMS Noise with $\mathbf{R} \mathbf{F}=\mathbf{5 0} \mathbf{~ k} \mathbf{\Omega}, \mathbf{C}_{\mathbf{s}}=\mathbf{3 0} \mathbf{p F}, \mathbf{C} \mathbf{F}=\mathbf{0 . 5} \mathbf{~ p F}$ |
| :--- | :--- | :--- |
| $\mathrm{R}_{\mathrm{F}}$ | $\sqrt{4 k T \times R_{F} \times f_{2} \times 1.57}$ | $94 \mu \mathrm{~V}$ |
| VEN Amp | $V E N \times \frac{C_{S}+C_{M}+C_{D}+C_{F}}{C_{F}} \times \sqrt{f_{3} \times 1.57}$ | $777.5 \mu \mathrm{~V}$ |
| IEN Amp | $I E N \times R_{F} \times \sqrt{f_{2} \times 1.57}$ |  |
| Total |  | $0.4 \mu \mathrm{~V}$ |

## HIGH SPEED JFET INPUT INSTRUMENTATION AMPLIFIER

Figure 66 shows an example of a high speed instrumentation amplifier with a high input impedance using the ADA4817-1/ ADA4817-2. The dc transfer function is

$$
\begin{equation*}
V_{\text {OUT }}=\left(V_{N}-V_{P}\right)\left(1+\frac{2 R_{F}}{R_{G}}\right) \tag{16}
\end{equation*}
$$

For $\mathrm{G}=1$, it is recommended that the feedback resistors for the two preamps be set to $0 \Omega$ and the gain resistor be open.

The system bandwidth for $\mathrm{G}=1$ is 400 MHz . For gains higher than 2, the bandwidth is set by the preamp, and it can be approximated by

$$
\text { In-amp-3dB }=\left(f_{C R} \times R_{G}\right) /\left(2 \times R_{F}\right)
$$

The match of resistor ratios, R1:R2 to R3:R4, primarily determine the common-mode rejection of the in-amp and it is estimated by

$$
\begin{equation*}
\frac{V_{O}}{V_{C M}}=\frac{(\delta 1-\delta 2)}{(1+\delta 1) \delta 2} \tag{17}
\end{equation*}
$$

The summing junction impedance for the preamps is equal to $R_{F} \| 0.5\left(R_{G}\right)$. Keep this value relatively low to improve the bandwidth response like in the previous example.


Figure 66. High Speed Instrumentation Amplifier

## ACTIVE LOW-PASS FILTER (LPF)

Active low-pass filters are used in many applications such as antialiasing filters and high frequency communication intermediate frequency (IF) strips.
With a 410 MHz gain bandwidth product and high slew rate, the ADA4817-1/ADA4817-2 is an ideal candidate for active filters. Moreover, thanks to the low input bias current provided by the FET stage, the ADA4817-1/ADA4817-2 eliminate any dc errors. Figure 67 shows the frequency response of 90 MHz and 45 MHz LPFs. In addition to the bandwidth requirements, the slew rate must be capable of supporting the full power bandwidth of the filter. In this case, a 90 MHz bandwidth with a 2 V p-p output swing requires at least $870 \mathrm{~V} / \mu \mathrm{s}$. This performance is achievable at 90 MHz only because of the wide bandwidth and high slew rate of the ADA4817-1/ADA4817-2.

The circuit shown in Figure 68 is a 4 -pole, Sallen-Key LPF. The filter comprises two identical cascaded Sallen-Key LPF sections, each with a fixed gain of $G=2$. The net gain of the filter is equal to $\mathrm{G}=4$ or 12 dB . The actual gain shown in Figure 67 is 12 dB . This gain does not take into account the output voltage being divided in half by the series matching termination resistor, $\mathrm{R}_{\mathrm{T}}$, and the load resistor.

Setting the resistors equal to each other greatly simplifies the design equations for the Sallen-Key filter. To achieve 90 MHz , set the R value to $182 \Omega$. However, if the R value is doubled, the corner frequency is cut in half to 45 MHz , which is a straightforward approach to tune the filter by multiplying the R value ( $182 \Omega$ ) by the ratio of 90 MHz and the new corner frequency in megahertz. Figure 67 shows the output of each stage of the filter and the two different filters corresponding to $\mathrm{R}=$ $182 \Omega$ and $\mathrm{R}=365 \Omega$. It is not recommended to increase the corner frequency beyond 90 MHz due to bandwidth and slew rate limitations, unless unity-gain stages are acceptable.

Resistor values are kept low for minimal noise contribution, offset voltage, and optimal frequency response. Due to the low capacitance values used in the filter circuit, the PCB layout and minimization of parasitics is critical. A few picofarads can detune the corner frequency, $\mathrm{f}_{\mathrm{C}}$, of the filter. The capacitor values shown in Figure 68 actually incorporate some stray PCB capacitance.

Capacitor selection is critical for optimal filter performance. Capacitors with low temperature coefficients, such as NPO ceramic capacitors and silver mica, are good choices for filter elements.


Figure 67. Low-Pass Filter Response


Figure 68. 4-Pole, Sallen-Key LPF (ADA4817-2)


Figure 69. Small Signal Transient Response (Low-Pass Filter)


Figure 70. Large Signal Transient Response (Low-Pass Filter)

## OUTLINE DIMENSIONS



*COMPLIANT TO JEDEC STANDARDS MO-220-WGGC-3 WITH EXCEPTION TO THE EXPOSED PAD

Figure 73.16-Lead Lead Frame Chip Scale Package [LFCSP]
$4 \mathrm{~mm} \times 4 \mathrm{~mm}$ Body and 0.75 mm Package Height (CP-16-20)
Dimensions shown in millimeters

## ORDERING GUIDE

| Model ${ }^{1}$ | Temperature <br> Range | Package Description | Package <br> Option | Ordering <br> Quantity | Marking <br> Code |
| :--- | :--- | :--- | :--- | :--- | :--- |
| ADA4817-1ACPZ-RL | $-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ | 8-Lead Lead Frame Chip Scale Package [LFCSP] | $\mathrm{CP}-8-13$ | 5000 |  |
| ADA4817-1ACPZ-R7 | $-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ | 8-Lead Lead Frame Chip Scale Package [LFCSP] | H 1 F |  |  |
| ADA4817-1ARDZ | $-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ | 8-Lead Standard Small Outline Package with Exposed Pad | RD-8-1 | 1500 |  |
| ADA4817-1ARDZ-RL | $-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ | 8-Lead Standard Small Outline Package with Exposed Pad | RD-8-1 | 2500 |  |
| ADA4817-1ARDZ-R7 | $-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ | 8-Lead Standard Small Outline Package with Exposed Pad | RD-8-1 | 1000 |  |
| ADA4817-2ACPZ-RL | $-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ | 16-Lead Lead Frame Chip Scale Package [LFCSP] | CP-16-20 | 5000 |  |
| ADA4817-2ACPZ-R7 | $-40^{\circ} \mathrm{C}$ to $+105^{\circ} \mathrm{C}$ | 16-Lead Lead Frame Chip Scale Package [LFCSP] | CP-16-20 | 1500 |  |
| ADA4817-2ACP-EBZ |  | Evaluation Board for 16-Lead LFCSP |  |  |  |

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[^0]:    ${ }^{1} Z=$ RoHS Compliant Part.

